NSN 5962-01-518-4022

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View Online at https://aerobasegroup.com/nsn/5962-01-518-4022

Body Length:	
0.740 inches	
Body Width:	
Between 0.460 inches and 0.520 inches	
Body Height:	
Between 0.045 inches and 0.115 inches	
Maximum Power Dissipation Rating:	
0.9 watts	
Operating Tempurature Range:	
-55.0/+125.0 degrees celsius	
Storage Tempurature Range:	
-65.0/+150.0 degrees celsius	
End Application:	
Nha pn 0n651867-2 cage 98230, e/i kgv-61a	
Features Provided:	
Electrostatic sensitive and radiation hardened	
Inclosure Material:	
Ceramic	
Inclosure Configuration:	
Flat pack	
Output Logic Form:	
Complementary-metal oxide-semiconductor logic	
Criticality Code Justification:	
Cbbl	
Current Rating Per Characteristic:	
110.00 milliamperes reverse current, dc absolute	
Terminal Surface Treatment:	
Gold	
Product Name:	
Microcircuit, memory, digital, radiation-hardened, cmos/sos, 8k x 8 static ram, monolithic silicon	1
Voltage Rating And Type Per Characteristic:	
-0.5 volts power source and 7.0 volts power source	
Time Rating Per Chacteristic:	
50.00 nanoseconds access	
Memory Device Type:	
Ram	
Memory Capacity:	
8kx8	
Nuclear Hardness Critical Feature:	
Hardened	
Terminal Type And Quantity:	
28 flat leads	

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Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

Yes - demil/mli

Fiig:

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